

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

2SK2394 — N-Channel Junction Silicon FET

Low-Noise HF Amplifier Applications

Applications

- · AM tuner RF amplifier
- · Low-noise amplifier

Features

- · Large | yfs |
- · Small Ciss
- Small-sized package permitting 2SK2394-applied sets to be made small slim
- · Ultralow noise figure

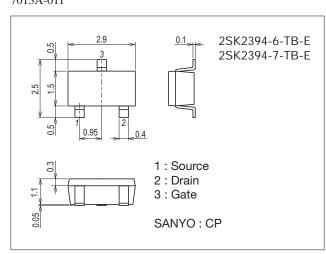
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSX}		15	V
Gate-to-Drain Voltage	V _{GDS}		-15	V
Gate Current	IG		10	mA
Drain Current	ID		50	mA
Allowable Power Dissipation	PD		200	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Package Dimensions

unit : mm (typ) 7013A-011



Product & Package Information

• Package : CP

• JEITA, JEDEC : SC-59, TO-236, SOT-23, TO-236AB

• Minimum Packing Quantity: 3,000 pcs./reel

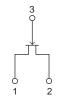
Packing Type: TB

O O O TB

Marking



Electrical Connection



Electrical Characteristics at Ta=25°C

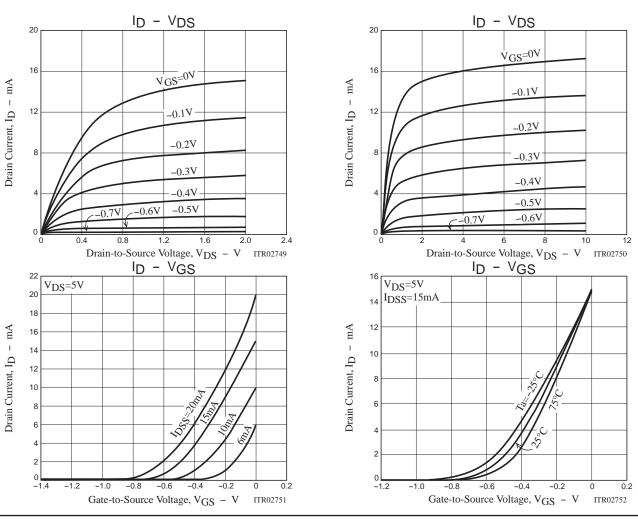
Parameter	Symbol	Conditions	Ratings			Unit
Parameter	Syllibol	Conditions	min	typ	max	UIIIL
Gate-to-Drain Breakdown Voltage	V(BR)GDS	IG=-10μA, VDS=0V	-15			V
Gate Cutoff Current	IGSS	V _{GS} =-10V, V _{DS} =0V			-1.0	nA
Cutoff Voltage	V _{GS} (off)	V _{DS} =5V, I _D =100μA	-0.3	-0.7	-1.5	V
Drain Current	IDSS	V _{DS} =5V, V _{GS} =0V	6.0*		32.0*	mA
Forward Transfer Admittance	yfs	V _{DS} =5V, V _{GS} =0V, f=1kHz	20	38		mS
Input Capacitance	Ciss	Vac EV Vac OV f 1MHz		10.0		pF
Reverse Transfer Capacitance	Crss	V _{DS} =5V, V _{GS} =0V, f=1MHz		2.9		pF
Noise Figure	NF	V_{DS} =5V, R_g =1k Ω , I_D =1mA, f =1kHz		1.0		dB

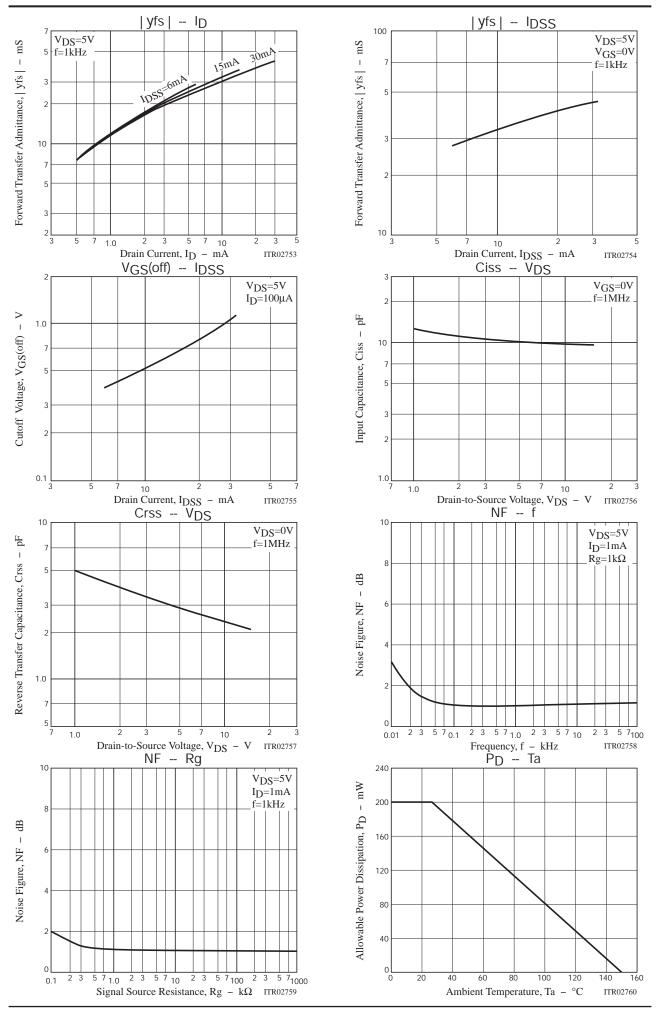
*: The 2SK2394 is classified by IDSS as follows: (unit: mA)

Rank	5	6	7	
IDSS	6.0 to 12.0	10.0 to 20.0	16.0 to 32.0	

Ordering Information

Device	Package	Shipping	memo
2SK2394-6-TB-E	СР	3,000pcs./reel	Pb Free
2SK2394-7-TB-E	СР	3,000pcs./reel	Pb Fiee



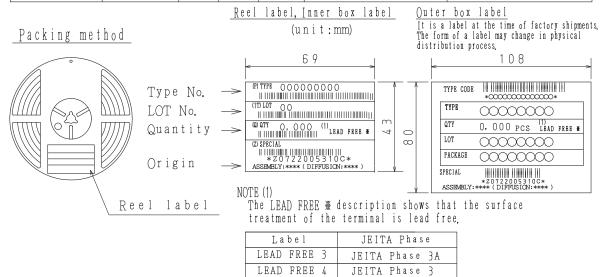


Embossed Taping Specification

2SK2394-6-TB-E, 2SK2394-7-TB-E

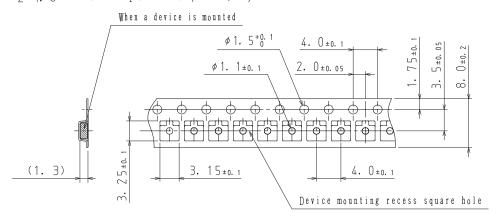
1. Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing format		
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
СР	СР	3, 000	15, 000	90,000	5 reels contained	6 inner boxes contained	
					Dimensions:mm (external)	Dimensions:mm (external)	
					183×72×185	440×195×210	

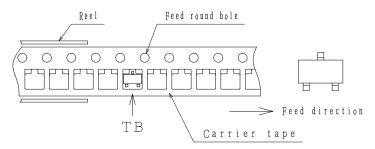


7. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction



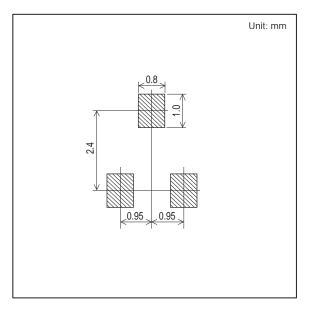
Those with one electrode terminal on the feed hole side·····TB

Outline Drawing

2SK2394-6-TB-E, 2SK2394-7-TB-E

Mass (g) Unit 0.013 For reference mm 0. 1+0. 1 0. 5+0. 25 2. 9±0. 15 A 3 1. 5±0. 15 2. 5±0. 2 2 0. 4^{+0. 1} 0. 1 M A 0. 5-0. 15 0. 95 0. 3±0.1 1, 1±0, 15 0. 05±0.05 *1:Lot indication

Land Pattern Example



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